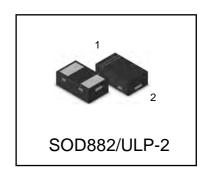
# SEMICONDUCTOR TECHNICAL DATA

# FTV3.3UUL2

# Transient Voltage Suppressors for ESD Protection General Description

The FTV3.3UUL2 is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space is at a premium.



# **Applications**

- Cellular phones audio
- MP3 players
- Digital cameras
- Portable applicationss
- mobile telephone



#### **Features**

Small Body Outline Dimensions:

0.039" x 0.024"(1.0 mm x 0.60 mm)

- Low Body Height: 0.020" (0.50 mm)
- Stand-off Voltage: 3.3 V -12 V
- Low Leakage
- Response Time is Typically < 1 ns
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- IEC61000-4-2 Level 4 ESD Protection
- These are Pb—Free Devices
- We declare that the material of product compliance with RoHS requirements.

### **Ordering information**

Device	Marking	Shipping		
FTV3.3UUL2	Е	10000/Tape&Reel		

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Air Contact Contact discharge		±15 ±8	kV kV
ESD Voltage Per Human Body Model		16	kV
Total Power Dissipation on FR-5 Board (Note 1)	PD	150	mW
@ T <sub>A</sub> =25			
Junction and Storage Temperature Range	TJ,TSTG	-55 to 150	
Lead Solder Temperature – Maximum (10	TL	260	
Second Duration)			

Stresses exceeding Maximum Ratings may damage the device. Maximum Rating are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

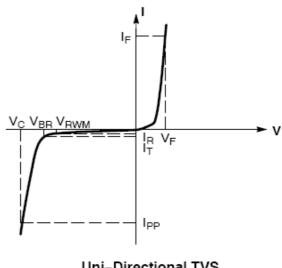
1. FR-5 = 1.0\*0.75\*0.62 in.





# **Electrical Parameter**

Symbol	Parameter
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub>
$V_{RWM}$	Working Peak Reverse Voltage
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>
I <sub>T</sub>	Test Current
$V_{BR}$	Breakdown Voltage @ I <sub>T</sub>
I <sub>F</sub>	Forward Current
P <sub>PK</sub>	Peak Power Dissipation
С	Max.Capacitance@VR=0 and f=1MHz



**Uni-Directional TVS** 

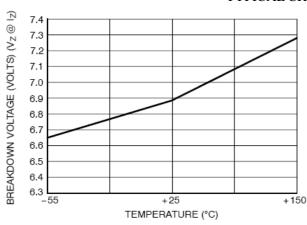
	$V_{RWM}$	$I_R$	$V_{BR}$	Ι <sub>Τ</sub>	I <sub>PP</sub>	Vc	$P_{PK}$	С
	(V)	(! A)	(V)	″ mA#	(A)	(V)	(W)	(pF)
Device		@	@ I <sub>T</sub>			@ Max I <sub>PP</sub>	(8*20 µs)	
		$V_{RWM}$	(Note 2)		(Note 3)	(Note 3)		
	Max	Max	Min		Max	Max	Тур	Тур
FTV3.3UUL2	3.3	2.5	5.0	1.0	9.8	10.4	102	80
FTV5.0UUL2	5.0	1.0	6.2	1.0	8.7	12.3	107	65
FTV12UUL2	12	1.0	13.3	1.0	5.9	23.7	140	30

- 1. Other voltage available upon request.
- 3. Surge current waveform per Figure 3.

Revision No: 0



#### TYPICAL CHARACTERISTICS



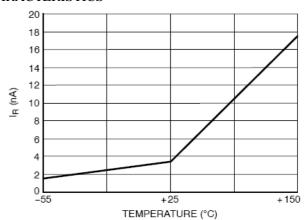


Figure 1. Typical Breakdown Voltage versus Temperature

Fig 2. Typical Leakage Current versus Temperature

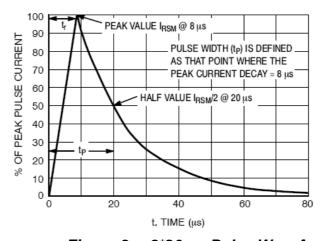


Figure 3. 8\*20 µs Pulse Waveform

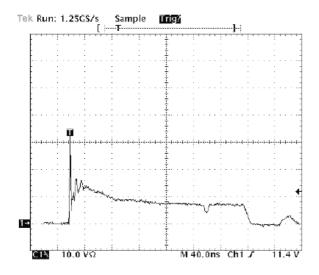


Figure 4. Positive 8kV contact per IEC 61000-4-2-LESD9D5.0T5G

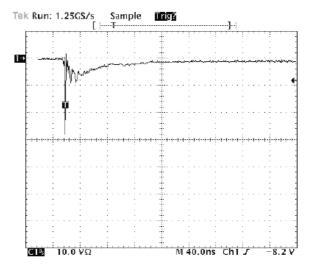


Fig 5. Negative 8kV contact per IEC 61000-4-2-LESD9D5.0T5G



# **SOD882 / ULP-2**

# **DIMENSION OUTLINE**

Unit:mm

